**HALOGEN** 

FREE

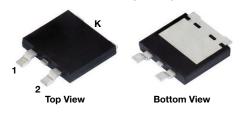


# Vishay General Semiconductor

# **Dual Trench MOS Barrier Schottky Rectifier**

Ultra Low  $V_F = 0.34 \text{ V}$  at  $I_F = 5 \text{ A}$ 

## TMBS® eSMP® Series TO-263AC (SMPD)



PIN 1	$\circ$	$\rightarrow$	ı K
			<del></del>
PIN 2	0—	<b>-</b>	HEATSINK

PRIMARY CHARACTERISTICS				
I <sub>F(AV)</sub>	2 x 15 A			
V <sub>RRM</sub>	60 V			
I <sub>FSM</sub>	200 A			
V <sub>F</sub> at I <sub>F</sub> = 15 A	0.49 V			
T <sub>J</sub> max.	150 °C			
Package	TO-263AC (SMPD)			
Diode variations	Dual common cathode			

#### **FEATURES**

- Trench MOS Schottky technology
- Very low profile typical height of 1.7 mm
- · Ideal for automated placement
- · Low forward voltage drop, low power losses
- · High efficiency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified available
  - Automotive ordering code; base P/NHM3
- Material categorization: for definitions of compliance please see <a href="https://www.vishav.com/doc?99912"><u>www.vishav.com/doc?99912</u></a>

#### TYPICAL APPLICATIONS

For use in high frequency DC/DC converters, switching power supplies, freewheeling diodes, OR-ing diode, and reverse battery protection.

### **MECHANICAL DATA**

Case: TO-263AC (SMPD)

Molding compound meets UL 94 V-0 flammability rating Base P/N-M3 - halogen-free, RoHS-compliant, and

commercial grade

Base P/NHM3 - halogen-free, RoHS-compliant, and

AEC-Q101 qualified

Base P/NHM3\_X - halogen-free, RoHS-compliant, and

AEC-Q101 qualified

("\_X" denotes revision code e.g. A, B,....)

Terminals: matte tin plated leads, solderable per

J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 2 whisker test, HM3 suffix meets JESD 201 class 2 whisker test

Polarity: as marked

MAXIMUM RATINGS (T <sub>A</sub> = 25 °C unless otherwise noted)					
PARAMETER		SYMBOL	V30D60CL	UNIT	
Maximum repetitive peak reverse voltage		V <sub>RRM</sub>	60	V	
Maximum average forward rectified current (fig. 1)	per device	- I <sub>F(AV)</sub>	30	Α	
	per diode		15		
Peak forward surge current 10 ms single half sine-wave superimposed on rated load		I <sub>FSM</sub>	200	Α	
Voltage rate of change (rated V <sub>R</sub> )		dV/dt	10 000	V/µs	
Operating junction and storage temperature range		T <sub>J</sub> , T <sub>STG</sub>	-40 to +150	°C	



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<b>ELECTRICAL CHARACTERISTICS</b> (T <sub>A</sub> = 25 °C unless otherwise noted)							
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT	
	I <sub>F</sub> = 5 A	T <sub>A</sub> = 25 °C	V <sub>F</sub> <sup>(1)</sup>	0.44	-	V	
	$I_F = 7.5 A$			0.47	-		
Instantaneous forward voltage per diede	I <sub>F</sub> = 15 A			0.55	0.61		
Instantaneous forward voltage per diode	I <sub>F</sub> = 5 A	T <sub>A</sub> = 125 °C		0.34	-		
	I <sub>F</sub> = 7.5 A			0.37	-		
	I <sub>F</sub> = 15 A			0.49	0.57		
Reverse current per diode		T <sub>A</sub> = 25 °C	I <sub>R</sub> <sup>(2)</sup>	-	4000	μA	
neverse current per diode		T <sub>A</sub> = 125 °C		35	110	mA	

#### **Notes**

(1) Pulse test: 300 µs pulse width, 1 % duty cycle

(2) Pulse test: pulse width ≤ 5 ms

THERMAL CHARACTERISTICS (T <sub>A</sub> = 25 °C unless otherwise noted)					
PARAMETER		SYMBOL	V30D60CL	UNIT	
Typical thermal resistance	per diode	- R <sub>θJC</sub>	1.8		
	per device		0.9	°C/W	
	per device	R <sub>0</sub> JA (1)(2)	45		

#### **Notes**

(1) The heat generated must be less than the thermal conductivity from junction-to-ambient: dP<sub>D</sub>/dT<sub>J</sub> < 1/R<sub>0,JA</sub>

(2) Free air, without heatsink

ORDERING INFORMATION (Example)						
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	DELIVERY MODE		
V30D60CL-M3/I	0.55	I	2000/reel	13" diameter plastic tape and reel		
V30D60CLHM3/I (1)	0.55	I	2000/reel	13" diameter plastic tape and reel		
V30D60CLHM3_A/I (1)	0.55	I	2000/reel	13" diameter plastic tape and reel		

#### Note

(1) AEC-Q101 qualified

## RATINGS AND CHARACTERISTICS CURVES (T<sub>A</sub> = 25 °C unless otherwise noted)

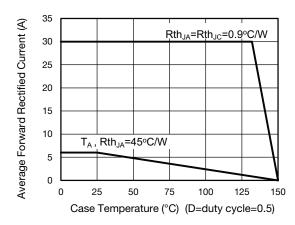


Fig. 1 - Forward Current Derating Curve

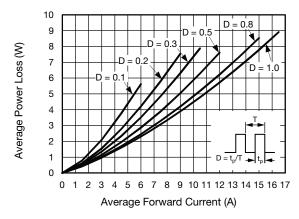


Fig. 2 - Forward Power Loss Characteristics Per Diode



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Junction to Ambient

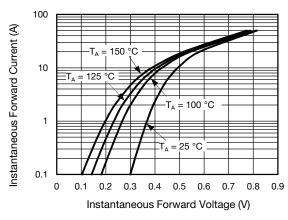
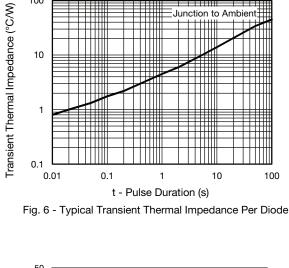


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode



100

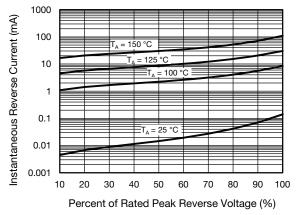


Fig. 4 - Typical Reverse Characteristics Per Diode

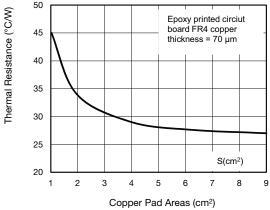


Fig. 7 - Thermal Resistance Junction-to-Ambient vs. Copper Pad Areas

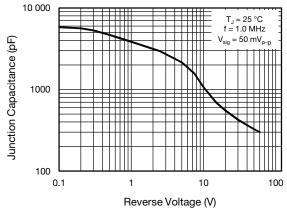


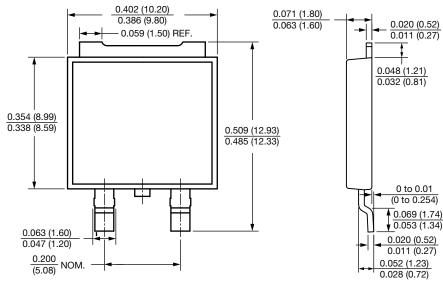
Fig. 5 - Typical Junction Capacitance Per Diode



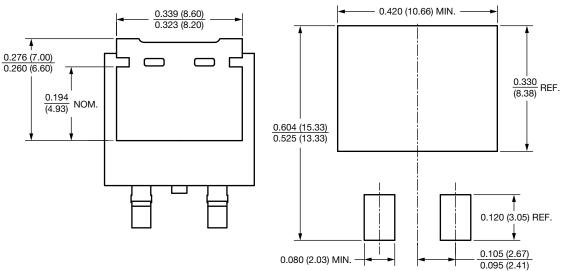
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## **PACKAGE OUTLINE DIMENSIONS** in inches (millimeters)

# TO-263AC (SMPD)



## **Mounting Pad Layout**





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Revision: 13-Jun-16 1 Document Number: 91000